







#### Characteristics **Typical** Guaranteed 0° to 50°C -54° to +85°C Frequency Small Signal Gain (min.) Gain Flatness (max.) Reverse Isolation Noise Figure (max.) Power Output @ 1 dB comp. (min.) IP3 IP2 Second Order Harmonic IP VSWR Input / Output (max.) DC Current @

## **Absolute Maximum Ratings**

Storage Temperature

Max. Case Temperature

Max. DC Voltage

Max. Continuous RF Input Power

Max. Short Term RF Input Power (1 minute max.)

Max. Peak Power (3 µsec max.)

"S" Series Burn-in Temperature (Case)

# Thermal Data: $V_{cc} =$

Thermal Resistance  $\theta_{ic}$ 

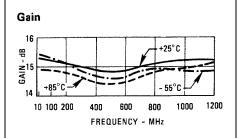
Transistor Power Dissipation P<sub>d</sub>

Junction Temperature Rise Above Case T<sub>ic</sub>

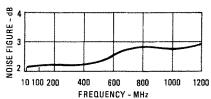
## **Outline Drawings**

Package	TO-8	Surface Mount	SMA Connectorized
Figure			
Model			

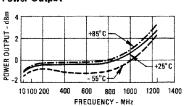
# Typical Performance @ 25°C



# Noise Figure

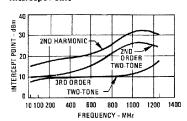


### Power Output\*



\* at 1 dB Gain Compression

### Intercept Point



### **VSWR**

